



## **Samsung MZ- V9P1T0 1 TB M.2 PCI Express 4.0 NVMe V- NAND MLC**

Model: MZ-V9P1T0GW

Manufacturer: SAMSUNG

EAN: 8806094594645

Product Code: 19815

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## **R5,307**

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Height: 24.3 mm | Depth: 8.2 mm | Interface: PCI Express 4.0 | Operating temperature (T-T): 0 - 70 °C | Weight: 28 g | Component for: PC/Game console | Power consumption (max): 7.8 W | Security algorithms: 256-bit AES | Width: 80 mm | Power consumption (average): 5.4 W | SSD capacity: 1 TB | Random write (4KB): 1550000 IOPS | Write speed: 6900 MB/s | TRIM support: Yes | Power consumption (idle): 0.05 W | S.M.A.R.T. support: Yes | Operating shock: 1500 G | Random read (4KB): 1200000 IOPS | SSD form factor: M.2 | NVMe version: 2.0 | Mean time between failures (MTBF): 1500000 h | NVMe: Yes | DevSlp (device sleep) support: Yes | Read speed: 7450 MB/s | Operating voltage: 3.3 V | Memory type: V-NAND MLC | Hardware encryption: Yes | M.2 SSD size: 2280 (22 x 80 mm)

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The product information provided is for reference purposes only. Technical specifications, photos, descriptions and prices may change without prior notice. The manufacturer and seller are not responsible for possible data discrepancies or typographical errors. We recommend checking the current information before purchasing.

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